

ESD9L5.0C

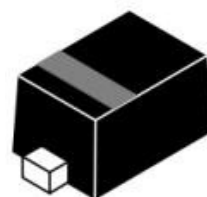
1-Line Bidirectional ESD Protection Diode

General description

The ESD9L5.0C is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time , make these parts ideal for ESD protection on designs where board space is at a premium

Features and benefits

- Low Capacitance 0.6 pF(Typ)
- Reverse stand-off voltage: 5V Max
- Low leakage current: nA Level
- Low Clamping Voltage
- Response time is typically < 1 ns
- IEC61000-4-2 Level 4 ESD Protection



SOD923

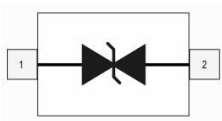
Application information

- 10/100/1000 Mbit/s Ethernet
- FireWire
- High- speed data lines
- Subscriber Identity Module (SIM) card protection
- Cellular handsets and accessories
- Portable electronics
- Communication systems
- Computers and peripherals
- Audio and video equipment
- Antenna protection

Ordering information

Device	Package	Marking	Packaging
ESD9L5.0C	SOD923	N	8000/Tape & Reel

Schematic & Pin configuration

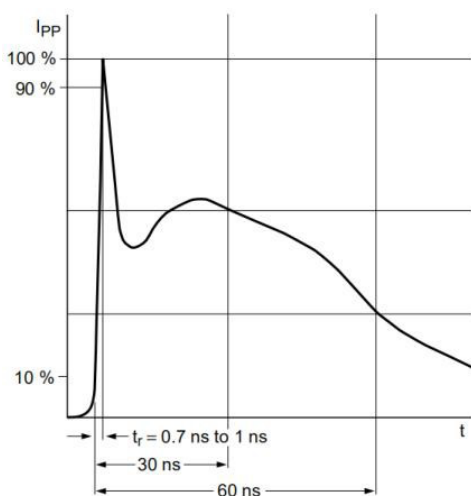
Simplified outline	Graphic symbol
	

Maximum Ratings ($T_{OP} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

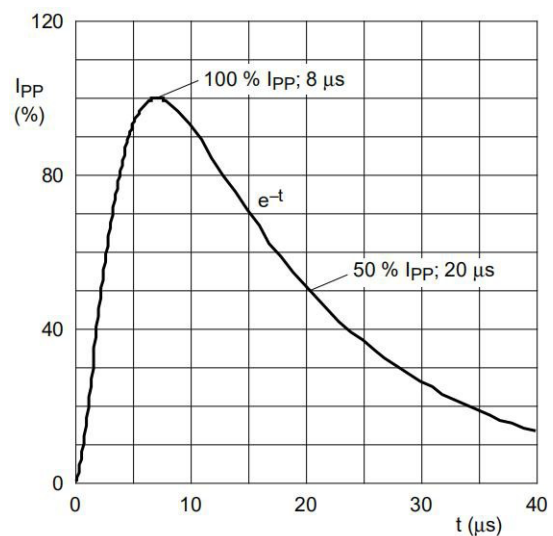
Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p = 8/20\mu\text{s}$)	P_{PPM}	45	W
Peak Pulse Current ($t_p = 8/20\mu\text{s}$)	I_{PPM}	3	A
ESD voltage IEC 61000-4-2 (air discharge)	V_{ESD}	15	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V_{ESD}	8	kV
Maximum lead temperature for soldering during 10s	T_L	260	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^{\circ}\text{C}$
Operating Temperature Range	T_{OP}	-40 to +125	$^{\circ}\text{C}$
Maximum junction temperature	T_j	150	$^{\circ}\text{C}$

Electrical Characteristics ($T_{OP} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Reverse Working Voltage	V_{RWM}	--	--	5.0	V	
Breakdown Voltage	V_{BR}	6.5	--	9.0	V	$I_T=1\text{mA}$
Leakage Current I_{Leak}	I_R	--	--	100	nA	$V_{RWM}=5\text{V}$
Clamping Voltage	V_C	--	--	15.0	V	$I_{PP}=3\text{A}, t_p=8/20\mu\text{s}$
Junction Capacitance	C_j	--	0.6	0.8	pF	$V_R=0\text{V}, f=1\text{MHz}$



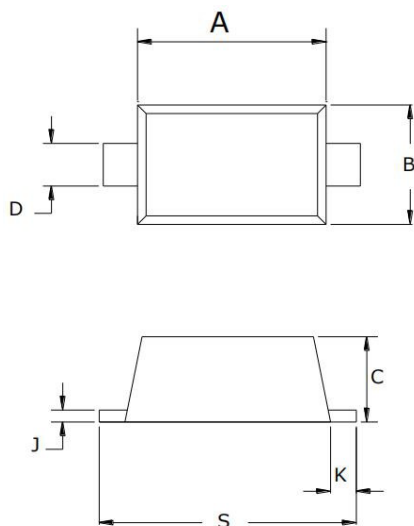
IEC61000-4-2 Waveform



IEC 61000-4-5 Waveform(8/20 μs pulse)

Package Outline Dimensions

SOD923



SYMBOL	MILLIMETERS	
	MIN	MAX
A	0.74	0.86
B	0.54	0.66
C	0.35	0.45
D	0.14	0.26
K	0.04	0.16
S	0.95	1.10

Soldering Footprint (mm)

